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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/902,177	07/10/2001	Tomotaka Fujisawa	09792909-5099	7492
26263 7	590 09/09/2003			
SONNENSCHEIN NATH & ROSENTHAL LLP P.O. BOX 061080			EXAMINER	
			ROSE, KIESHA L	
WACKER DRIVE STATION, SEARS TOWER		SIIA L		
CHICAGO, IL	60606-1080		ART UNIT	PAPER NUMBER
	,		2822	

DATE MAILED: 09/09/2003

Please find below and/or attached an Office communication concerning this application or proceeding.

· <u>4</u>			part
	Application No.	Applicant(s)	<u></u>
C.	09/902,177	FUJISAWA ET AL.	
Office Action Summary	Examin r	Art Unit	
	Kiesha L. Rose	2822	
Th MAILING DATE of this communication ap	opears on the cover shell to	vith the correspond nc address	
Period for Reply A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1. after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a replace of the interval	136(a). In no event, however, may a ply within the statutory minimum of the d will apply and will expire SIX (6) MC te, cause the application to become A ing date of this communication, even it	reply be timely filed irty (30) days will be considered timely. NTHS from the mailing date of this communicati BANDONED (35 U.S.C. § 133).	ion.
1) Responsive to communication(s) filed on 23			
· /	his action is non-final.		
3) Since this application is in condition for allow closed in accordance with the practice unde Disposition of Claims	wance except for formal m er <i>Ex parte Quayl</i> e, 1935 C	atters, prosecution as to the ments .D. 11, 453 O.G. 213.	3 is
4) Claim(s) is/are pending in the application	tion.		
4a) Of the above claim(s) is/are withdra	awn from consideration.		
5)⊠ Claim(s) <u>11</u> is/are allowed.			
6)⊠ Claim(s) <u>1,6,8 and 10</u> is/are rejected.			
7)⊠ Claim(s) <u>3 and 4</u> is/are objected to.			
8) Claim(s) are subject to restriction and/	or election requirement.		
Application Papers			
9)☐ The specification is objected to by the Examin			
10)⊠ The drawing(s) filed on <u>6 June 2003</u> is/are: a)		•	
Applicant may not request that any objection to t			
11) The proposed drawing correction filed on		disapproved by the Examiner.	
If approved, corrected drawings are required in re	• •		
12) The oath or declaration is objected to by the E	examiner.		
Priority under 35 U.S.C. §§ 119 and 120		0.440(-) (-1) (5)	
13) Acknowledgment is made of a claim for foreign	gn priority under 35 U.S.C	. § 119(a)-(a) or (f).	
a) All b) Some * c) None of:			
1. Certified copies of the priority documer		A 15 C AL	
2. Certified copies of the priority documer			
 3. Copies of the certified copies of the pri- application from the International B * See the attached detailed Office action for a list 	Bureau (PCT Rule 17.2(a))		
14) Acknowledgment is made of a claim for domes	stic priority under 35 U.S.C	s. § 119(e) (to a provisional applica	ation).
a) \square The translation of the foreign language parts) \square Acknowledgment is made of a claim for domest			
Attachment(s)			
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice of	v Summary (PTO-413) Paper No(s) f Informal Patent Application (PTO-152)	-·

Art Unit: 2822

DETAILED ACTION

This Office Action is in response to the RCE filed 23 July 2003.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1 and 8 are rejected under 35 U.S.C. 103(a) as being unpatentable over Applicant's Prior Art (Figure 1b).

Applicant's Prior Art (Fig. 1b) discloses a photodiode comprising a first conductivity type first semiconductor layer (11), first conductivity type second semiconductor layer (substrate)(10), a second conductivity type semiconductor layer (12) formed at a surface layer portion of semiconductor layer (11) and a depletion layer (V), where the end face of the layer on the side of the first semiconductor layer (11) are within no more than a predetermined distance. In regards to the sensitivity of the photodiode to light of a first wavelength and to a second wavelength that is different from the first are made substantially the same, since the Applicant's Prior Art (Fig. 1b) has the same structural configuration as the claimed invention.

Claims 1, 6, 8 and 10 are rejected under 35 U.S.C. 103(a) as being unpatentable over Sakamoto et al. (U.S. Patent 5,886,374).

Art Unit: 2822

Sakamoto discloses a photodiode (Fig. 4) that contains a first conductivity type second semiconductor substrate (41) with a concentration of 1017, a first conductivity type semiconductor layer (42) formed on substrate, a second conductivity type semiconductor layer (43) formed on first conductivity type layer (42), where the first conductivity type layer has a concentration lower than the substrate. In regards to the sensitivity of the photodiode to light of a first wavelength and to a second wavelength which is different from the first are made substantially the same, since the Sakamoto has the same structural configuration as the claimed invention. Sakamoto discloses the claimed invention except for the impurity concentrations of the p-type and n-type semiconductor layers to be between certain concentrations. It would have been obvious to one having ordinary skill in the art at the time the invention was made to have the impurity concentrations of the p-type and n-type semiconductor layers to be between certain concentrations, since it has been held that where the general conditions of a claim are disclosed in the prior art, discovering the optimum or workable ranges involves only routine skill in the art. In re Aller, 105 USPQ 233 (1955).

Allowable Subject Matter

Claim 11 is allowed.

Claims 3 and 4 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Art Unit: 2822

Response to Arguments

Applicant's argument, see Page 5, filed 23 July 2003, with respect to the depletion layer to spread to a first and second predetermined amounts of 3-6 and 2-7 have been fully considered and are persuasive. The rejections of the predetermined amounts of spacing of the depletion layer to be between 3-6 and 2-7 of claims 3 and 4 have been withdrawn. In regards to the argument dealing with the depletion layer spreading to a first and second amount the APA discloses the claimed invention and is structurally the same and therefore when biased would spread to a certain distance since claim 1 does not disclose a certain predetermined distance. Therefore this rejection stands.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Kiesha L. Rose whose telephone number is 703-605-4212. The examiner can normally be reached on M-F 8:30-6:00 off 1st Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Amir Zarabian can be reached on 703-308-4905. The fax phone number for the organization where this application or proceeding is assigned is (703) 872-9306.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.

Art Unit: 2822

Page 5

AMIR ZARABIAN
SUPERVISORY PATENT EXAMINER
TECHNOLOGY CENTER 2800